

October 1987 Revised March 2002

CD4010C Hex Buffers (Non-Inverting)

General Description

The CD4010C hex buffers are monolithic complementary MOS (CMOS) integrated circuits. The N- and P-channel enhancement mode transistors provide a symmetrical circuit with output swings essentially equal to the supply voltage. This results in high noise immunity over a wide supply voltage range. No DC power other than that caused by leakage current is consumed during static conditions. All inputs are protected against static discharge. These gates may be used as hex buffers, CMOS to DTL or TTL interface or as CMOS current drivers. Conversion ranges are from 3V to 15V providing $V_{\rm CC} \leq V_{\rm DD}$. The devices also have buffered outputs which improve transfer characteristics by providing very high gain.

Features

■ Wide supply voltage range: 3.0V to 15V

■ Low power: 100 nW (typ.)

■ High noise immunity: 0.45 V_{DD} (typ.)

■ High current sinking: 8 mA (min.) at $V_O = 0.5V$ capability: and $V_{DD} = 10V$

Applications

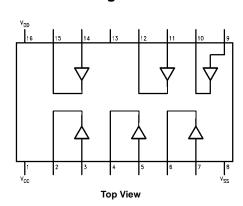
- Automotive
- · Data terminals
- Instrumentation
- · Medical electronics
- · Alarm system
- · Industrial controls
- · Remote metering
- Computers

Ordering Code:

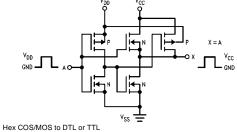
Order Number	Package Number	Package Description				
CD4010CM	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow				
CD4010CN	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide				

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Schematic Diagram



converter (inverting).

Connect V_{CC} to DTL or TTL supply.

Connect V_{DD} to COS/MOS supply.

Absolute Maximum Ratings(Note 1)

Power Dissipation (P_D)

 Dual-In-Line
 700 mW

 Small Outline
 500 mW

Lead Temperature (T_L)

(Soldering, 10 seconds) 260°C

Operating Range (V_{DD}) $V_{SS} + 3V$ to $V_{SS} + 15V$

Note 1: "Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits."

Note 2: This device should not be connected to circuits with the power on because high transient voltage may cause permanent damage.

DC Electrical Characteristics

		Conditions	Limits								
Symbol	Characteristics		–55°C		+25°C			+125°C		Units	
			Min	Max	Min	Тур	Max	Min	Max		
I _{CC}	Quiescent Device	V _{DD} = 5.0V		0.3		0.01	0.3		20		
	Current	$V_{DD} = 10V$		0.5		0.01	0.5		30	μА	
P _D	Quiescent Device	V _{DD} = 5.0V		1.5		0.05	1.5		100	μW	
	Dissipation/Package	$V_{DD} = 10V$		5.0		0.1	5.0		300		
V _{OL}	Output Voltage	V _{DD} = 5.0V		0.01		0	0.01		0.05	٧	
	LOW Level	$V_{DD} = 10V$		0.01		0	0.01		0.05		
V _{OH}	Output Voltage	V _{DD} = 5.0V	4.99		4.99	5		4.95		٧	
	HIGH Level	$V_{DD} = 10V$	9.99		9.99	10		9.95			
V _{NL}	Noise Immunity	$V_{DD} = 5.0V, V_{O} \ge 1.5$	1.6		1.5	2.25		1.4		٧	
	(All Inputs)	$V_{DD} = 10V, V_{O} \ge 3.0$	3.2		3	4.5		2.9			
V _{NH}	Noise Immunity	$V_{DD} = 5.0V, V_{O} \ge 3.5$	1.4		1.5	2.25		1.5		V	
	(All Inputs)	$V_{DD} = 10V, V_{O} \ge 7.0$	2.9		3	4.5		3		V	
I _D N	Output Drive Current	$V_{DD} = 5.0V, 0.4 = V_0$	3.75		3	4		2.1		mA	
	N-Channel (Note 3)	$V_{DD} = 10V, 0.5 = V_0$	10		8	10		5.6			
I _D P	Output Drive Current	$V_{DD} = 5.0V, 2.5 = V_0$	-1.85		-1.25	-1.75		-0.9		mA	
	P-Channel (Note 3)	$V_{DD} = 10V, 9.5 = V_0$	-0.9		-0.6	-0.8		-0.4			
I _I	Input Current					10				pА	

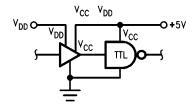
Note 3: I_DN and I_DP are tested one output at a time.

AC Electrical Characteristics (Note 4) $T_A = 25^{\circ}c, C_L = 15 \text{ pF, unless otherwise noted. Typical Temperature coefficient for all values of $V_{DD} = 0.3\%^{\circ}C$}$

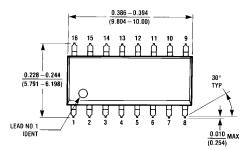
		Test Conditions					
Symbol	Characteristics		V _{DD}	Min	Тур	Max	Units
			(Volts)				
t _{PHL}	Propagation Delay Time:	$V_{CC} = V_{DD}$	5	_	15	70	
t _{PLH}	HIGH-to-LOW Level (t _{PHL})		10	_	10	40	ns
		$V_{DD} = 10V$		_	10	35	
		$V_{CC} = 5V$					
	LOW-to-HIGH Level (t _{PLH})	$V_{CC} = V_{DD}$	5	_	50	100	
			10	_	25	70	
		$V_{DD} = 10V$		_	15	40	ns
		V _{CC} = 5V					
t _{THL}	Transition Time:	$V_{CC} = V_{DD}$	5	_	20	60	ns
t _{TLH}	HIGH-to-LOW Level (t _{THL})		10	_	16	50	
	LOW-to-HIGH Level (t _{TLH})	$V_{CC} = V_{DD}$	5	_	80	160	ns
			10	_	50	120	
	Input Capacitance (C _I)	Any Input		_	5	_	pF

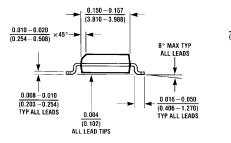
Note 4: AC Parameters are guaranteed by DC correlated testing.

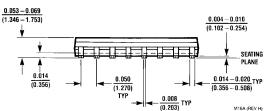
Typical Application



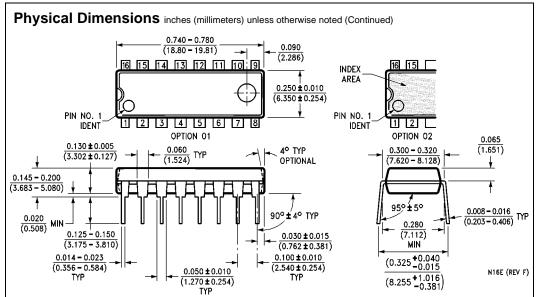
Physical Dimensions inches (millimeters) unless otherwise noted







16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Package Number M16A



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N16E

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